NSN 5962-01-193-5814

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View Online at https://aerobasegroup.com/nsn/5962-01-193-5814

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Body Length:
Between 1.230 inches and 1.285 inches
Body Width:
Between 0.510 inches and 0.545 inches
Body Height:
Between 0.135 inches and 0.165 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Simulator an/ulq-13
Features Provided:
Hermetically sealed and static operation and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
22 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:

Yes - demil/mli

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